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## Dose dependence of magnetism in Co-doped TiO<sub>2</sub>

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### Abstract

The dose dependence of magnetism in Co-implanted TiO<sub>2</sub> rutile was investigated using the magneto-optic Kerr effect method at room temperature. The (100)- and (001)-oriented single-crystalline rutile TiO<sub>2</sub> plates were used as substrates and implanted by Co ions with a varying dose range of 0.25–1.50 × 10<sup>17</sup> ions/cm<sup>2</sup>. We observed paramagnetic behaviour for the low dose doped samples, but obtain clear hysteretic-like behaviour for intermediate and high dose doped samples. For the intermediate implantation doses of Co, ferromagnetic behaviour can be explained by the F-center (oxygen vacancies) exchange mechanism, while for the highest implantation dose, in addition to Co substitution on Ti sites, formation of Co nanoclusters may take place within the TiO<sub>2</sub> irradiated region.

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The discovery of room temperature ferromagnetism in Co-doped anatase TiO<sub>2</sub> [1] has generated much interest in the Co:TiO<sub>2</sub> system as a potential oxide-based diluted magnetic semiconductor (DMS) [2–7]. In spite of rather extensive studies in this field, the origin of the observed ferromagnetism is still unclear. Several investigations explained that cobalt ions in thin TiO<sub>2</sub> films exist in a +2 oxidation state, consistent with ferromagnetism that originates from Co substitution on Ti sites [2], while in other publications the origin of ferromagnetism is reported to be due to the precipitation of cobalt metal clusters [8,9]. Recently, we have reported room temperature ferromagnetism and in-plane magnetic anisotropy of single-crystalline rutile

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